

LOW-VOLTAGE 10-BIT BUS SWITCH

IDT74CBTLV3384

FEATURES:

- 5Ω A/B bi-directional bus switch
- · Isolation under power-off conditions
- · Over-voltage tolerant
- · Latch-up performance exceeds 100mA
- Vcc = 2.3V 3.6V, Normal Range
- ESD > 2000V per MIL-STD-883, Method 3015;
 > 200V using machine model (C = 200pF, R = 0)
- · Available in QSOP and TSSOP packages

APPLICATIONS:

· 3.3V High Speed Bus Switching and Bus Isolation

DESCRIPTION:

The CBTLV3384 is a ten bit high-speed bus switch with low on-state resistance of the switch allowing connections to be made with minimal propagation delay.

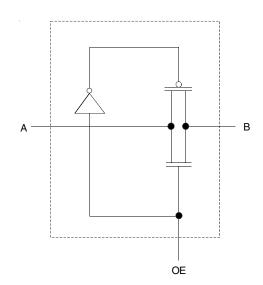
The device is organized as dual 5-bit bus switches with separate outputenable (\overline{OE}) inputs, to allow use as two 5-bit bus switches or one 10-bit bus switch. When \overline{OE} is low, the associated 5-bit bus switch is on and A port is connected to B port. When \overline{OE} is high, the switch is open, and a high-impedance state exists between the two ports.

To ensure the high-impedance state during power up or power down, \overline{OE} should be tied to VCC through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

FUNCTIONAL BLOCK DIAGRAM

1A1 3 SW 2 1B1 1A5 11 SW 10 1B5 1OE 1 SW 2 1B1 2A1 14 SW 15 2B1 2A2 22 SW 10 2B5

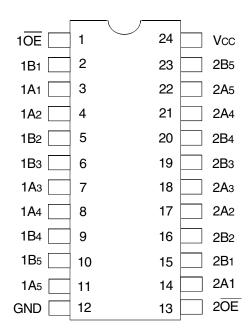
SIMPLIFIED SCHEMATIC, EACH SWITCH



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PIN CONFIGURATION



QSOP/TSSOP TOP VIEW

ABSOLUTE MAXIMUM RATINGS(1)

	5		
Symbol	Description	Max	Unit
Vcc	SupplyVoltage Range	-0.5 to +4.6	
Vı	Input Voltage Range	-0.5 to +4.6	V
	Continuous Channel Current	128	mA
lıĸ	Input Clamp Current, VI/O < 0	– 50	mA
Tstg	Storage Temperature	-65 to +150	°C

NOTE:

1. Stresses greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

FUNCTION TABLE(1)

Inp	out	Inputs/Outputs		
10E	20E	1B1 - 1B5	2B1 - 2B5	
L	L	1A1 - 1A5	2 A 1 - 2 A 5	
L	Н	1A1 - 1A5	Z	
Н	L	Z	2 A 1 - 2 A 5	
Н	Н	Z	Z	

NOTE:

1. H = HIGH Voltage Level

L = LOW Voltage Level

Z = High Impedance

OPERATING CHARACTERISTICS, TA = 25°C(1)

Symbol	Parameter	Test Conditions	Min.	Max.	Unit
Vcc	Supply Voltage		2.3	3.6	V
VIH	High-Level Control Input Voltage	Vcc = 2.3V to 2.7V	1.7	_	V
		Vcc = 2.7V to 3.6V	2	_	
VIL	Low-Level Control Input Voltage	Vcc = 2.3V to 2.7V	_	0.7	V
		Vcc = 2.7V to 3.6V	_	0.8	
TA	Operating Free-Air Temperature		-40	85	°C

NOTE:

1. All unused control inputs of the device must be held at Vcc or GND to ensure proper device operation.

DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE

Following Conditions Apply Unless Otherwise Specified:

Operating Conditions: TA = -40°C to +85°C

Symbol	Parameter	Test Conditions		Min.	Тур.	Max.	Unit
Vik	Control Inputs, Data I/O	Vcc = 3V, II = -18mA		_	_	-1.2	V
lı	Control Inputs, Data I/O	Vcc = 3.6V, VI = Vcc or GN	D	T -	_	±1	μΑ
loz	Data I/O	Vcc = 3.6V, Vo = 0 or 3.6V,	switch disabled	T -	_	5	μΑ
loff		Vcc = 0, Vi or Vo = 0 to 3.6\	/	_	_	50	μΑ
Icc		Vcc = 3.6V, lo = 0, Vı = Vc	Vcc = 3.6V, Io = 0, VI = Vcc or GND		<u> </u>	10	μΑ
$\Delta lcc^{(1)}$	Control Inputs	Vcc = 3.6V, one input at 3V,	Vcc = 3.6V, one input at 3V, other inputs at Vcc or GND		_	300	μΑ
Сі	Control Inputs	Vı = 3V or 0	VI = 3V or 0		4	_	pF
CIO(OFF)		Vo = 3V or 0, $\overline{\text{OE}}$ = Vcc		T -	7	_	pF
	Max. at Vcc = 2.3V	Vı = 0	Io = 64mA	<u> </u>	5	8	
	Typ. at Vcc = 2.5V		Io = 24mA	_	5	8	
Ron ⁽²⁾		VI = 1.7V	Io = 15mA	_	27	40	Ω
		VI = 0	Io = 64mA	_	5	7	
	Vcc = 3V		Io = 24mA	T -	5	7	1
		Vı = 2.4V	Io = 15mA	_	10	15	1

NOTES:

- 1. The increase in supply current is attributable to each current that is at the specified voltage level rather than Vcc or GND.
- 2. This is measured by the voltage drop between the A and B terminals at the indicated current through the switch. On-state resistance is determined by the lower of the voltages of the two (A or B) terminals.

SWITCHING CHARACTERISTICS

		Vcc = 2.5V ± 0.2V		$Vcc = 3.3V \pm 0.3V$		
Symbol	Parameter	Min.	Max.	Min.	Max.	Unit
t PD ⁽¹⁾	Propagation Delay	-	0.15	-	0.25	ns
	A to B or B to A					
ten	Output Enable Time	1	5	1	4.3	ns
	OE to A or B					
tois	Output Disable Time	1	5.5	1	5.5	ns
	OE to A or B					

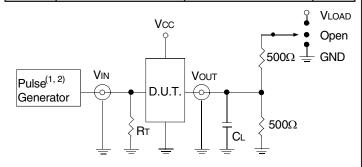
NOTE:

^{1.} The propagation delay is the calculated RC time constant of the typical on-state resistance of the switch and the specified load capacitance driven by an ideal voltage source (zero output impedance).

TEST CIRCUITS AND WAVEFORMS

TEST CONDITIONS

Symbol	$Vcc^{(1)} = 3.3V \pm 0.3V$	Vcc ⁽²⁾ =2.5V±0.2V	Unit
VLOAD	6	2 x Vcc	V
VIH	3	Vcc	V
VT	1.5	Vcc/2	V
VLZ	300	150	mV
VHZ	300	150	mV
CL	50	30	рF



Test Circuits for All Outputs

DEFINITIONS:

CL = Load capacitance: includes jig and probe capacitance.

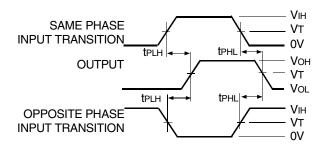
RT = Termination resistance: should be equal to ZouT of the Pulse Generator.

NOTES:

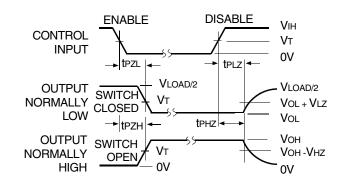
- 1. Pulse Generator for All Pulses: Rate \leq 10MHz; tF \leq 2.5ns; tR \leq 2.5ns.
- 2. Pulse Generator for All Pulses: Rate \leq 10MHz; tF \leq 2ns; tR \leq 2.5ns.

SWITCH POSITION

Test	Switch
tplz/tpzl	Vload
tpHz/tpzH	GND
teo	Open

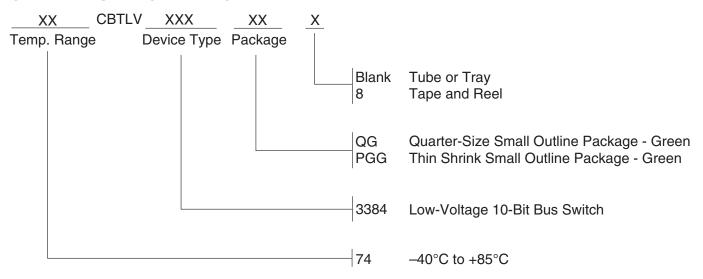


Propagation Delay



Enable and Disable Times

ORDERING INFORMATION



Datasheet Document History

12/18/2014 Pg. 5 Updated the ordering information by removing non RoHS part and by adding Tape and Reel information.



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IDT (Integrated Device Technology):

74CBTLV3384PGG 74CBTLV3384QG 74CBTLV3384PGG8 74CBTLV3384QG8